



State-selective intersystem crossing in nitrogen-vacancy centers

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The intersystem crossing (ISC) is an important process in many solid-state atomlike impurities. For example, it allows the electronic spin state of the nitrogen-vacancy (NV) center in diamond to be initialized and read out using optical fields at ambient temperatures. This capability has enabled a wide array of applications in metrology and quantum information science. Here, we develop a microscopic model of the state-selective ISC from the optical excited state manifold of the NV center. By correlating the electron-phonon interactions that mediate the ISC with those that induce population dynamics within the NV center's excited state manifold and those that produce the phonon sidebands of its optical transitions, we quantitatively demonstrate that our model is consistent with recent ISC measurements. Furthermore, our model constrains the unknown energy spacings between the center's spin-singlet and spin-triplet levels. Finally, we discuss prospects to engineer the ISC in order to improve the spin initialization and readout fidelities of NV centers.

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I. INTRODUCTION

The nitrogen-vacancy (NV) center in diamond has recently been applied to a diverse range of room-temperature applications in metrology and quantum information science. NV centers have been used to sense such quantities as the temperature and magnetic fields of living cells [1,2], the magnetic field of a single electron spin [3], the magnetic field noise of a few molecules [4,5], an electric field equivalent to a single electron at a distance of 35 nm [6], and pressures of up to 60 GPa [7]. NV centers can also function as room-temperature quantum registers, where the electronic spin can be coherently coupled to the nitrogen nucleus [8] by decoherence-protected gates [9] and proximal ¹³C nuclear spins with second-long coherence times [10] can serve as storage qubits. These applications depend on the optical initialization and readout of the NV center's electronic spin, techniques which are enabled by the intersystem crossing (ISC) mechanism.

The ISC mechanism, which refers to nonradiative transitions between states of different spin multiplicity, has been previously investigated both theoretically [11] and by indirect experimental methods, such as measurements of spin-resolved fluorescence lifetimes [12–14] and spin dynamics under nonresonant optical excitation [11,14,15]. While the previous theoretical investigation of the ISC mechanism established that it involves both spin-orbit and electron-phonon interactions, it did not provide a detailed microscopic model of the mechanism. Recently, the ISC rates from each of the fine-structure states of the center's optical excited level have been measured at cryogenic temperatures [16]. These new measurements complete a comprehensive experimental picture of the ISC from the optical excited level, thereby motivating new theoretical efforts to develop a detailed model of the ISC mechanism.

In this paper, we present such a microscopic model of the state-selective ISC from the optical excited state manifold of the NV center. We show that the electron-phonon interactions

that mediate the ISC are closely linked with those that induce population dynamics within the NV center's excited state manifold and those that produce the phonon sidebands (PSBs) of its optical transitions. This correspondence enables us to use recent measurements of the phonon-induced population mixing rate [16] and the PSB of the visible transition [17] as experimental inputs to our model, and we quantitatively demonstrate that our model is consistent with recent ISC measurements. Additionally, our model constrains the unknown energy spacings between the center's spin-singlet and spin-triplet levels to spectral regions that may be probed in future measurements. The identification of these energy spacings will resolve the most significant unknown aspect of the center's electronic structure. Finally, we discuss how our new understanding yields prospects to engineer the ISC to improve the spin initialization and readout fidelities of NV centers at room temperature.

This work is structured as follows: In Sec. II, we describe the NV center, present the formalism of our model of the ISC mechanism, and explicitly calculate the ISC rates from different states in the ³E manifold. We also calculate the phonon-induced mixing rate between $|E_x\rangle$ and $|E_y\rangle$, which enables us to extract the NV-phonon coupling strength from prior experimental observations. In Sec. III, we compare the results of our model to recently measured state-selective ISC rates at cryogenic temperatures, which enables us to place bounds on the energy spacing between the spin-triplet and -singlet states. In Sec. IV, we extend our model to higher temperature and show that it is consistent with previous observations of spin-dependent fluorescence lifetimes. We conclude in Sec. V by suggesting future theoretical and experimental directions.

II. ISC MODEL

A. Level structure of NV center

The NV center is a point defect of C_{3v} symmetry that consists of a substitutional nitrogen atom adjacent to a vacancy in the diamond lattice. In the negative charge state,

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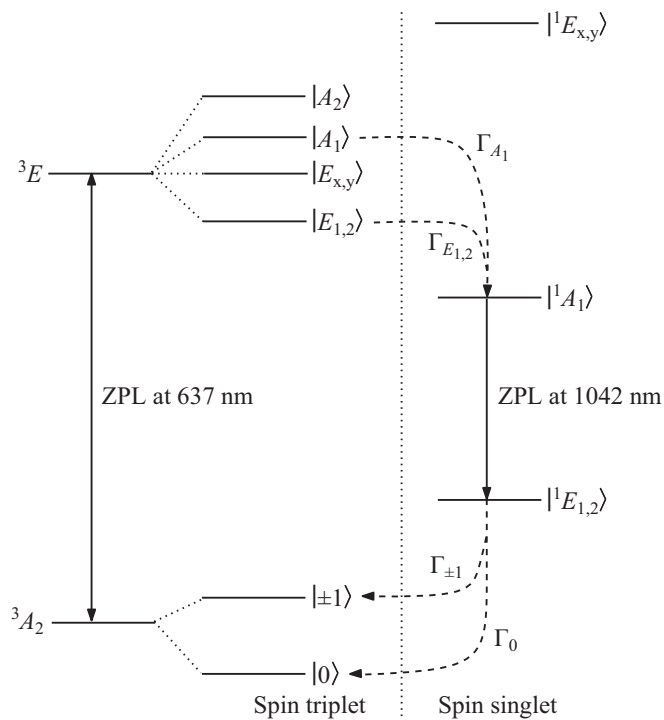


FIG. 1. Electronic structure of the NV center, including the fine-structure states of the spin-triplet levels, the ZPL transitions of the center's visible and infrared resonances (solid arrows), and the state-selective nonradiative ISCs between the spin-triplet and -singlet levels (dashed arrows). Γ_x denote the rates of the individual ISC transitions.

six electrons occupy the four dangling sp^3 orbitals of the nitrogen and the vacancy's three nearest-neighbor carbon atoms [18,19]. The four sp^3 atomic orbitals linearly combine to form four symmetry-adapted molecular orbitals (a'_1 , a_1 , e_x , e_y), such that the ground electronic configuration is $a_1^2 a_1^2 e^2$. The ground electronic state (labeled 3A_2) is an orbital-singlet, spin-triplet manifold (see Fig. 1 for the NV center's electronic structure). Within 3A_2 , there is a doublet of states with $m_s = \pm 1$ spin projection along the N-V axis (labeled $|\pm 1\rangle$) located 2.87 GHz above one state with $m_s = 0$ (labeled $|0\rangle$). The ground electronic configuration also contains an orbital-singlet, spin-singlet state $|{}^1A_1\rangle$ that is higher in energy than the orbital-doublet, spin-singlet states $|{}^1E_{1,2}\rangle$. The $|{}^1A_1\rangle$ and $|{}^1E_{1,2}\rangle$ singlet states are coupled by an optical transition with a zero-phonon line (ZPL) at 1042 nm [20]. The first excited electronic configuration ($a_1^2 a_1 e^3$) consists of the optical excited orbital-doublet, spin-triplet manifold 3E , as well as the orbital doublet, spin-singlet states $|{}^1E_{x,y}\rangle$. The 3E manifold is coupled to the 3A_2 ground-state manifold by an optical transition with a ZPL at 637 nm. The two orbital states and three spin states of the 3E manifold combine to give a total of six fine-structure states: two (labeled $|E_x\rangle$ and $|E_y\rangle$) have zero spin angular momentum projections, while the other four (labeled $|A_1\rangle$, $|A_2\rangle$, $|E_1\rangle$, and $|E_2\rangle$) are entangled states of nonzero spin and orbital angular momentum projections.

The spin dynamics of the NV center under optical illumination are driven by radiative transitions between states of the same spin multiplicity as well as nonradiative ISCs between states of different spin multiplicity (see Fig. 1). There are two

distinct ISCs: from the optical excited 3E manifold to the higher-energy singlet state $|{}^1A_1\rangle$, and from the lower-energy singlet states $|{}^1E_{1,2}\rangle$ to the ground 3A_2 manifold. The ISC from the 3E manifold may occur from either $|A_1\rangle$ with rate Γ_{A_1} or from $|E_{1,2}\rangle$ with rate $\Gamma_{E_{1,2}} \approx \Gamma_{A_1}/2$ [16]. While direct ISCs from $|E_{x,y}\rangle$ and $|A_2\rangle$ are not forbidden, their rates have been established to be negligible compared to Γ_{A_1} and $\Gamma_{E_{1,2}}$ at cryogenic temperatures [16]. This hierarchy reflects the directness of the physical process that couples each 3E state to the singlet states: the ISCs from $|A_1\rangle$ and $|E_{1,2}\rangle$ are, respectively, mediated by first- and second-order processes, as discussed in Secs. II C and II D, and the lowest-order allowed ISC processes from $|E_{x,y}\rangle$ and $|A_2\rangle$ would be third order, as discussed in Ref. [16]. The ISC from the 3E manifold is thus highly state selective. The ISC to the 3A_2 manifold occurs from $|{}^1E_{1,2}\rangle$ to either $|0\rangle$ with rate Γ_0 or $|\pm 1\rangle$ with rate $\Gamma_{\pm 1}$. The ratio $\Gamma_0/\Gamma_{\pm 1}$ appears to vary between centers with observed values in the range 1.1–2 [14,15]. While further investigations are required, it is clear that there is no strong state selectivity of the ISC to the 3A_2 manifold.

Under optical excitation, the radiative transitions between the 3A_2 and 3E manifolds conserve electronic spin projection, whereas the highly state-selective ISC transitions from the 3E manifold to $|{}^1A_1\rangle$ preferentially depopulate $|A_1\rangle$ and $|E_{1,2}\rangle$, and the ISC transitions from $|{}^1E_{1,2}\rangle$ to the 3A_2 manifold serve to repopulate the ground state for the next optical cycle. The preferential nonradiative depopulation of $|A_1\rangle$ and $|E_{1,2}\rangle$ gives rise to optical spin readout because these states have lower quantum yield [21]. Since the nonradiative repopulation of the 3A_2 manifold from $|{}^1E_{1,2}\rangle$ does not appear to be comparably state selective, the preferential nonradiative depopulation of $|A_1\rangle$ and $|E_{1,2}\rangle$ is also predominantly responsible for the optical initialization of the electronic spin into $|0\rangle$ [21]. Given the central role of the ISC from the optical excited 3E manifold to $|{}^1A_1\rangle$ in the NV optical-spin cycle, we focus our attention on developing a microscopic model of this ISC.

B. ISC mechanism

ISCs from the 3E manifold to the $|{}^1A_1\rangle$ state occur in two stages (see Fig. 2): (1) an energy-conserving transition from the initial state within the 3E manifold to a resonant excited vibrational level of the $|{}^1A_1\rangle$ state, and (2) relaxation of the excited vibrational level to the ground (or thermally occupied) vibrational level of $|{}^1A_1\rangle$. The first stage requires a change in both the electron spin and orbital states as well as the lattice vibrational state, and is thus mediated by a combination of spin-orbit (SO) and electron-phonon interactions. The second stage is mediated by phonon-phonon interactions, which enables the vibrational excitation to dissipate into propagating phonon modes. As the vibrational relaxation occurs on picosecond time scales [22], the ISC rate is defined by the initial electronic transition.

The model of these transitions requires the description of the quasicontinuum of vibronic levels of the 3E and $|{}^1A_1\rangle$ electronic states. Coulombic interactions between the NV center's electrons and proximal nuclei induce a local A_1 -symmetric deformation of the diamond lattice. Because this Coulomb force depends on the electronic charge density, the equilibrium lattice configuration depends on the NV

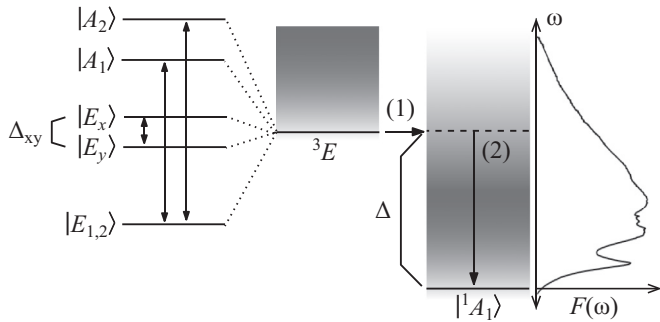


FIG. 2. Schematic of (left) the phonon-induced mixing within the 3E manifold and (right) the stages of the ISC from the 3E manifold to the $|{}^1A_1\rangle$ state. The phonon mixing transitions within the 3E manifold are depicted by solid arrows. Δ_{xy} is the strain-induced splitting of the $|E_{x,y}\rangle$ states. The shaded regions denote the quasi-continuum of the vibrational levels of 3E and $|{}^1A_1\rangle$. The stages of the ISC, which are described in the text, are denoted by the arrows labeled (1) and (2). The ISC vibrational overlap function $F(\omega)$, as approximated by the visible emission PSB, is depicted on the far right. This provides a visual representation of how the 3E - $|{}^1A_1\rangle$ energy separation Δ influences the ISC rate.

center's electronic orbital state [23,24]. Adopting the Born-Oppenheimer and harmonic approximations, the dependence of the NV center's energy on the positions of proximal nuclei can be modeled as a series of quadratic potentials centered on a common electronic state-dependent equilibrium point. Thus, the vibronic levels of each electronic state take the direct product form: $\{|E_{1,2}\rangle, |E_{x,y}\rangle, |A_1\rangle, |A_2\rangle\} \otimes \{|\chi_{v_n}\rangle\}$ and $|{}^1A_1\rangle \otimes \{|\chi'_{v_n}\rangle\}$, where $|\chi_{v_n}\rangle$ and $|\chi'_{v_n}\rangle$ are the n th vibrational levels of 3E and $|{}^1A_1\rangle$, respectively, with vibrational energies v_n [25,26]. Here, n denotes the set of occupation numbers $\{m_i\}$ of all vibrational modes of the specified electronic state. The n th vibrational level and energy are then given by $|\chi_{v_n}\rangle = \prod_i |m_i\rangle$ and $v_n = \sum_i m_i \omega_i$, respectively, where ω_i is the energy of the i th vibrational mode.

Electron-phonon interactions with A_1 -symmetric phonon modes do not couple electronic states, but allow transitions between the vibrational levels of each electronic state. As a consequence, there exist nonzero overlaps $|\langle \chi_{v_n} | \chi'_{v_n} \rangle|^2$ of different vibrational levels of 3E and $|{}^1A_1\rangle$. Since the $|{}^1A_1\rangle$ state belongs to the same electronic configuration as the ground 3A_2 manifold, their electron densities are similar, and thus the vibrational overlaps $|\langle \chi_{v_n} | \chi'_{v_n} \rangle|^2$ are expected to be well approximated by those between the 3E and 3A_2 manifolds that are observed in the visible emission PSB [17].

Electron-phonon interactions with E -symmetric phonon modes couple electronic orbital states. Consequently, they can drive spin-conserving transitions between the states of the 3E manifold (see Fig. 2). The interactions with E -symmetric phonons within the 3E manifold are described by [18]

$$\hat{H}_{e-p} = \sum_{p,k} \hat{V}_{e-p}^p \lambda_{p,k} (\hat{a}_{p,k}^\dagger + \hat{a}_{p,k}), \quad (1)$$

where

$$\begin{aligned} \hat{V}_{e-p}^1 = & |E_x\rangle\langle E_x| - |E_y\rangle\langle E_y| + (|E_1\rangle\langle A_1| \\ & - |E_2\rangle\langle A_2| + 2|{}^1E_1\rangle\langle {}^1A_1| + \text{H.c.}), \end{aligned}$$

$$\begin{aligned} \hat{V}_{e-p}^2 = & |E_x\rangle\langle E_y| + i|E_2\rangle\langle A_1| - i|E_1\rangle\langle A_2| \\ & + 2|{}^1E_2\rangle\langle {}^1A_1| + \text{H.c.}, \end{aligned} \quad (2)$$

$\hat{a}_{p,k}^\dagger$ and $\hat{a}_{p,k}$ are the creation and annihilation operators of an E -symmetric phonon with wave vector k and polarization $p = \{1, 2\}$ [27], and $\lambda_{p,k}$ is the associated phononic coupling rate.

The SO interaction has two components. The axial SO interaction [$\propto \lambda_{\parallel} l_z s_z$, where s_z (l_z) is the z component of the electronic spin (orbital angular momentum)] defines observable aspects of the 3E fine structure but does not couple 3E states with $|m_s| = 1$ to spin-singlet states. On the contrary, the transverse SO interaction [$\propto \lambda_{\perp} (l_x s_x + l_y s_y)$] cannot be directly observed in the 3E fine structure [18,19], but gives rise to the coupling

$$\hat{H}_{SO} = \sqrt{2} \hbar \lambda_{\perp} (|A_1\rangle\langle {}^1A_1| + |E_1\rangle\langle {}^1E_1| + i|E_2\rangle\langle {}^1E_2|) + \text{H.c.} \quad (3)$$

In the following sections, we explicitly calculate the ISC rates from and the phonon-induced mixing rate between different 3E states. We perform this calculation by treating \hat{H}_{SO} and \hat{H}_{e-p} as time-dependent perturbations to the vibronic states of 3E and $|{}^1A_1\rangle$ defined by electron-phonon interactions with A_1 -symmetric phonons. The vibrational overlap function of the visible emission PSB is used to approximate the vibrational overlaps between states in the 3E manifold and $|{}^1A_1\rangle$. We perform the calculations in the low-temperature limit applicable to the cryogenic temperatures at which the state-selective ISC rates were recently measured [16], where only the ground vibrational levels of the 3E manifold are populated prior to the ISC transitions to $|{}^1A_1\rangle$. We extend our calculations to higher temperatures in Sec IV.

C. ISC rate from $|A_1\rangle$

Transverse SO interaction directly couples $|A_1\rangle$ with the resonant excited vibrational states of $|{}^1A_1\rangle$. Consequently, this rate can be calculated by the application of first-order Fermi's golden rule

$$\Gamma_{A_1} = 4\pi \hbar \lambda_{\perp}^2 \sum_n |\langle \chi_0 | \chi'_{v_n} \rangle|^2 \delta(v_n - \Delta), \quad (4)$$

where Δ is the energy spacing between 3E and $|{}^1A_1\rangle$ (neglecting fine structure of 3E). The ISC rate is proportional to the overlap between $|\chi_0\rangle$ (the ground vibrational state of $|A_1\rangle$) and $|\chi'_{v_n}\rangle$ (an excited vibrational level of $|{}^1A_1\rangle$ that is separated from $|{}^1A_1\rangle$ by an energy spacing v_n). We perform the sum over n in order to define a vibrational overlap function

$$\begin{aligned} F(\Delta) = & \sum_n |\langle \chi_0 | \chi'_{v_n} \rangle|^2 \delta(v_n - \Delta) \\ = & \overline{|\langle \chi_0 | \chi'_{\Delta} \rangle|^2} \rho(\Delta), \end{aligned} \quad (5)$$

where $\rho(\Delta)$ is the density of excited vibrational states that are resonant with $|A_1\rangle$ and the average is over all such states.

We substitute the vibrational overlap function, which encapsulates all relevant information about the quasi-continuum of $|{}^1A_1\rangle$ vibrational modes, into Eq. (4) to find

$$\Gamma_{A_1} = 4\pi \hbar \lambda_{\perp}^2 F(\Delta). \quad (6)$$

D. ISC rate from $|E_{1,2}\rangle$

An analogous first-order ISC process is not responsible for the ISC transition from $|E_{1,2}\rangle$; $|E_{1,2}\rangle$ cannot decay to $|^1A_1\rangle$ because there is no SO coupling between these states, and we expect decay to $|^1E_{1,2}\rangle$ to be negligible because the $|^1A_1\rangle - |^1E_{1,2}\rangle$ energy spacing (1190 meV [28]) is large compared to the extent of the phonon sideband (~ 500 meV [17,29]). Instead, ISC decay from $|E_{1,2}\rangle$ is the result of a second-order process wherein phonons of E symmetry couple $|E_{1,2}\rangle$ to $|A_1\rangle$ and $|A_1\rangle$ is SO coupled to $|^1A_1\rangle$. We calculate the ISC rate from $|E_{1,2}\rangle$ using second-order Fermi's golden rule and find

$$\Gamma_{E_{1,2}} = 2\pi\hbar^3 \sum_{n,p,k} \left| \frac{\sqrt{2}\lambda_{\perp}\lambda_{p,k}}{\omega_k} \right|^2 |\langle \chi_0 | \chi'_{v_n} \rangle|^2 [(n_{p,k} + 1) \times \delta(v_n + \omega_k - \Delta) + n_{p,k} \delta(v_n - \omega_k - \Delta)], \quad (7)$$

where ω_k is the energy of a phonon of wave vector k . The two distinct terms within the sum correspond to phonon emission and absorption.

We introduce the k -independent phonon energy ω , over which we integrate to pull out the polarization-specific phonon spectral density

$$J_p(\omega) = \frac{\pi\hbar}{2} \sum_k \lambda_{p,k}^2 \delta(\omega - \omega_k). \quad (8)$$

In the linear dispersion regime, where the wavelength of acoustic phonons is much larger than the lattice spacing, the coupling strength for interactions mediated by deformations of the lattice is given by the standard deformation potential ($\lambda_{p,k} \propto \sqrt{\omega_k}$ [30]) and the phonon density of states is described by the Debye model ($\text{DOS} \propto \omega^2$). The total spectral density is therefore

$$J(\omega) = J_p(\omega) = \eta \omega^3, \quad (9)$$

where η parametrizes the coupling strength between the states of the 3E manifold and E -symmetric acoustic phonons.

We insert this spectral density and the appropriate vibrational overlap functions to find

$$\Gamma_{E_{1,2}} = 8\hbar^2\lambda_{\perp}^2\eta \int_0^{\Omega} \omega \{ [n(\omega) + 1]F(\Delta - \omega) + n(\omega)F(\Delta + \omega) \} d\omega, \quad (10)$$

where

$$n(\omega) = \frac{1}{e^{\omega/k_B T} - 1} \quad (11)$$

is the thermal occupation of a phonon mode of energy ω . We assume a cutoff energy Ω for acoustic phonons.

To illustrate the range of phonon energies that contribute to $\Gamma_{E_{1,2}}$, we define a rate $\tilde{\Gamma}_{E_{1,2}}(\omega)$ that is mediated only by E -symmetric phonons of energy ω , such that $\Gamma_{E_{1,2}} = \int_0^{\Omega} \tilde{\Gamma}_{E_{1,2}}(\omega) d\omega$. The contributions to $\tilde{\Gamma}_{E_{1,2}}(\omega)$ due to phonon emission and absorption are shown in Fig. 3. The dominant contribution to $\Gamma_{E_{1,2}}$ comes from high-energy phonon modes, whose thermal occupations are negligible at $T < 26$ K. This conclusion is valid for all values of Δ because the vibrational overlap function $F(\Delta \pm \omega)$ changes slowly on the scale of $k_B T \lesssim 5$ meV. We may therefore neglect thermal

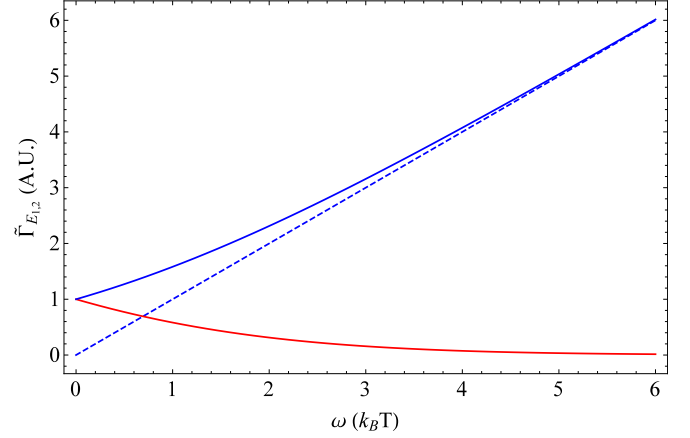


FIG. 3. (Color online) ISC rate $\tilde{\Gamma}_{E_{1,2}}$ from $|E_{1,2}\rangle$ as a function of the energy of the mediating E -symmetric phonon. Contributions due to phonon absorption (red line), stimulated and spontaneous emission (blue line), and spontaneous emission only (blue dashed line) are shown. At $T = 5$ K, $k_B T = 2\pi\hbar \times 104$ GHz = 0.43 meV. We assume that the vibrational overlap function $F(\Delta \pm \omega)$ is flat for the range of ω (2.6 meV) shown.

occupation of the mediating phonon modes and take the low-temperature limit of $\Gamma_{E_{1,2}}$ when working at cryogenic temperatures, assertions that we will justify in Sec. III B.

In the low-temperature limit, the ISC rate from $|E_{1,2}\rangle$ is given by

$$\Gamma_{E_{1,2}} = \frac{2}{\pi} \hbar \eta \Gamma_{A_1} \int_0^{\min(\Delta, \Omega)} \omega \frac{F(\Delta - \omega)}{F(\Delta)} d\omega. \quad (12)$$

The range of phonon modes that contribute to $\Gamma_{E_{1,2}}$ is bounded either by the cutoff energy Ω , or by the fact that $F(\Delta - \omega) = 0$ for $\omega \geq \Delta$ at low temperature (see Sec. IV A).

If second-order ISC processes that use $|^1E_{1,2}\rangle$ as intermediate states are taken into account, as described in the Appendix, then $\Gamma_{E_{1,2}}$ is modified to

$$\Gamma_{E_{1,2}} = \frac{2}{\pi} \hbar \eta \Gamma_{A_1} \int_0^{\min(\Delta, \Omega)} \omega^3 \left(\frac{1}{\omega} - \frac{2}{\Delta + \Delta'} \right)^2 \times \frac{F(\Delta - \omega)}{F(\Delta)} d\omega. \quad (13)$$

We note that this secondary ISC process only contributes significantly to the total ISC rate from $|E_{1,2}\rangle$ because it interferes coherently with the primary ISC process, which uses $|A_1\rangle$ as the intermediate state.

E. Phonon-induced mixing rate

We now explicitly calculate the phonon-induced mixing rates between the states in the 3E manifold. Doing so will enable us to extract the value of η , which parametrizes the NV-phonon coupling strength, from a temperature-dependent measurement of the $|E_x\rangle - |E_y\rangle$ mixing rate [16].

We use a technique similar to that used to calculate the ISC rate from $|E_{1,2}\rangle$ in the previous section. We begin with the mixing rate between $|E_x\rangle$ and $|E_y\rangle$. The dominant contribution to the mixing rate in the low-strain regime ($\Delta_{xy} = \mathcal{E}_{E_x} - \mathcal{E}_{E_y} = 2\pi\hbar \times 3.9$ GHz for the experiment in

question [16]) is from a two-phonon Raman process wherein one phonon is emitted and another is absorbed [31]. Following Ref. [31], we use second-order Fermi's golden rule to find that this mixing rate is

$$\Gamma_{\text{Mix}} = \frac{32\hbar}{\pi} \int_0^\infty n(\omega)[n(\omega + \Delta_{xy}) + 1] \times \left[\frac{J_1(\omega + \Delta_{xy})J_2(\omega)}{(\omega + \Delta_{xy})^2} + \frac{J_1(\omega)J_2(\omega + \Delta_{xy})}{\omega^2} \right] d\omega. \quad (14)$$

We substitute the expression for the spectral density $J_p(\omega)$ in the acoustic limit [Eq. (9)]. We keep only the highest-order term in ω/Δ_{xy} because the integrand in Eq. (14) is only appreciable for $\omega \sim k_B T \gg \Delta_{xy}$ and, as in the previous section, we define a mixing rate

$$\tilde{\Gamma}_{\text{Mix}}(\omega) = \frac{64}{\pi} \hbar \eta^2 \omega^4 n(\omega)[n(\omega + \Delta_{xy}) + 1] \quad (15)$$

that is mediated only by phonons of energies ω and $\omega + \Delta_{xy}$. As is shown in Fig. 4, contributions to the total mixing rate $\Gamma_{\text{Mix}} = \int_0^\infty \tilde{\Gamma}_{\text{Mix}}(\omega) d\omega$ are dominated by phonon modes with energy of order $k_B T$. Higher-energy phonons have significantly larger spectral densities, but the emission-absorption Raman process requires that the phonon mode of energy ω have non-negligible thermal occupation. Unlike with the ISC rate from $|E_{1,2}\rangle$, which is mediated mainly by high-energy phonons, the contributions to the mixing rate from phonon modes with energies larger than approximately 20 meV are exponentially suppressed at cryogenic temperatures, so we need not impose a cutoff energy for the available phonon modes.

We therefore find the total mixing rate

$$\Gamma_{\text{Mix}} = \frac{64}{\pi} \hbar \alpha \eta^2 k_B^5 T^5. \quad (16)$$

The numeric constant α is given by the integral

$$\alpha = \int_0^\infty \frac{1}{e^x - 1} \left(\frac{1}{e^{x+x_\Delta} - 1} + 1 \right) x^4 dx, \quad (17)$$

where $x = \omega/k_B T$ and $x_\Delta = \Delta_{xy}/k_B T$.

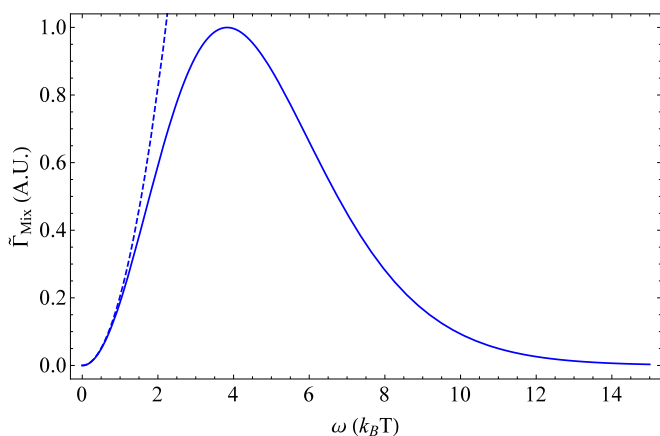


FIG. 4. (Color online) Mixing rate $\tilde{\Gamma}_{\text{Mix}}$ as a function of the energy of the lower-energy mediating E -symmetric phonons. At $T = 5$ K, $k_B T = 2\pi\hbar \times 104$ GHz = 0.43 meV. The dashed line shows ω^2 , properly scaled, for comparison.

The mixing rates due to other processes are negligible. There are two alternate two-phonon processes, wherein both phonons are either absorbed or emitted, but they do not conserve energy and contribute negligibly, respectively. There is a direct one-phonon emission process, for which we calculate a transition rate

$$\Gamma_{\text{Mix}}^{(1\text{-ph})} = 4\eta[n(\Delta_{xy}) + 1]\Delta_{xy}^3 \approx 4\eta k_B \Delta_{xy}^2 T, \quad (18)$$

where the approximation is true for $\Delta_{xy} \ll k_B T$. This one-phonon rate is negligible when the strain splitting Δ_{xy} is small. For example, we calculate that a strain splitting of at least $\Delta_{xy}/2\pi\hbar = 18$ GHz is required to produce a measurable (≥ 0.5 MHz) one-phonon mixing rate at 5 K, whereas this analysis assumes $\Delta_{xy}/2\pi\hbar = 3.9$ GHz to match Ref. [16]. We note that a mixing rate that scales as T rather than T^5 would be more difficult to suppress using standard liquid-helium cryogenic techniques with $T \sim 5$ K. This consideration may explain why a previous measurement of phonon-induced mixing [31] found that the $|E_x\rangle - |E_y\rangle$ mixing rate was increased for NV centers with higher strain splittings (44 to 81 GHz, compared with 8 and 9 GHz) and did not appear to asymptote to a constant value at low temperatures to the same degree. The effect of the one-phonon mixing process may be even more substantial for NV centers, such as those formed by nitrogen implantation or placed inside nanofabricated structures, where damage to the local crystalline structure may induce a large strain splitting.

We now calculate the phonon-induced mixing rate between $|A_1\rangle$ and $|A_2\rangle$. This calculation is similar to that of the $|E_x\rangle - |E_y\rangle$ mixing rate. Instead of coupling and splitting the energies of $|E_x\rangle$ and $|E_y\rangle$, phonons of E symmetry couple $|A_1\rangle$ and $|A_2\rangle$ with $|E_1\rangle$ and $|E_2\rangle$. The fact that the intermediate electronic state ($|E_1\rangle$ or $|E_2\rangle$) is not degenerate with the initial or final state ($|A_1\rangle$ or $|A_2\rangle$) gives rise to a resonance condition when the energy of the emitted phonon is equal to the splitting between the initial and intermediate electronic states. This resonance condition, however, is irrelevant because the mixing process is dominated by phonons with energy $\omega \approx 4k_B T \approx 2\pi\hbar \times 400$ GHz, as shown in Fig. 4. Because the typical phonon energy is large compared to the 10 GHz splitting between $|A_1\rangle$ or $|A_2\rangle$ and $|E_{1,2}\rangle$, the mixing rate between $|A_1\rangle$ and $|A_2\rangle$ is unaffected by the detuning of the intermediate state and is also given by Eq. (16). The mixing rate between $|E_1\rangle$ and $|E_2\rangle$ is also given by Eq. (16) for the same reasons, although mixing between these two states cannot be observed directly using the techniques employed in Ref. [16] because the ISC rates from both states are the same.

Further, both $|A_1\rangle$ and $|A_2\rangle$ are coupled to both $|E_1\rangle$ and $|E_2\rangle$ by a one-phonon process, whose rate in all four cases is given by Eq. (18) with Δ_{xy} replaced by the appropriate energy splitting. For the reverse process, from $|E_1\rangle$ and $|E_2\rangle$ to $|A_1\rangle$ and $|A_2\rangle$, we replace $[n(\Delta_{xy}) + 1]$ with $n(\Delta_{xy})$, but the result is the same in the limit $\Delta_{xy} \ll k_B T$. Thus, the cyclicity of the nominally closed $|\pm 1\rangle - |A_2\rangle$ Λ system, like that of the $|0\rangle - |E_x\rangle$ cycling transition, may be degraded in NV centers with high strain splittings.

III. COMPARISON TO MEASUREMENTS

A. ISC rate from $|A_1\rangle$

We now compare the results of the preceding calculations to the measured state-selective ISC rates [16], with the goal of extracting the previously unknown energy spacing between the spin-singlet and spin-triplet levels. We first compare the calculated ISC rate from $|A_1\rangle$, which depends on the transverse SO coupling rate λ_\perp and the vibrational overlap function $F(\omega)$, with the measured $\Gamma_{A_1}/2\pi = 16.0 \pm 0.6$ MHz.

Most of the uncertainty in our theoretical prediction of Γ_{A_1} is the result of the lack of precision with which λ_\perp is known. The axial SO coupling rate $\lambda_\parallel = 5.33 \pm 0.03$ GHz has been measured precisely through spectroscopy of the 3E manifold [32], but λ_\perp cannot be determined through similar methods. An approximate theoretical argument implies that $\lambda_\perp \sim \lambda_\parallel$. Due to the similar mass and charge of nitrogen and carbon atoms, the C_{3v} symmetric structure of the NV center is only a small departure from the T_d symmetric structure of a vacancy in the diamond lattice. Given that $\lambda_\perp = \lambda_\parallel$ precisely in T_d symmetry, it is expected that $\lambda_\perp \sim \lambda_\parallel$ in the slightly perturbed symmetry of the NV center [33]. This argument is supported by preliminary *ab initio* calculations that estimate the ratio $\lambda_\perp/\lambda_\parallel \sim 1.15\text{--}1.33$ [18,34]. To reflect the uncertainty in the value of λ_\perp , we select a confidence band of $\lambda_\perp/\lambda_\parallel = 1.2 \pm 0.2$.

We extract the vibrational overlap function $F(\omega)$ from spectroscopy of the ${}^3E \rightarrow {}^3A_2$ emission PSB conducted at 4 K [17]. As we describe in Sec. IV A, $F(\omega)$ is, in principle, temperature dependent. However, the dominant and lowest-energy feature in the one-phonon spectrum extracted from the ${}^3E \rightarrow {}^3A_2$ PSB occurs at 64 meV $= k_B \times 118$ K [17]. Because phonons with such large energies are negligibly occupied at temperatures below 26 K, we assume that $F(\omega)$ is effectively temperature independent for our analysis of the low-temperature ISC rate.

In Fig. 5, we compare the measured and predicted values of Γ_{A_1} in order to extract Δ , the previously unknown $|A_1\rangle - |{}^1A_1\rangle$ energy splitting. This analysis confines Δ to two regions: around 43 meV, and from $\Delta_- = 344$ meV to $\Delta_+ = 430$ meV with a central value of $\Delta_0 = 392$ meV. We exclude values of Δ below 148 meV because the predicted ISC rate from $|E_{1,2}\rangle$ would be significantly lower than the observed rate, as explained in Sec. III B. The uncertainty in Δ is dominated by the uncertainty in λ_\perp , so a precise calculation of the $\lambda_\perp/\lambda_\parallel$ ratio could narrow the bounds on Δ considerably.

B. ISC rate from $|E_{1,2}\rangle$

We also compare the measured and predicted ratios of the ISC rates from $|E_{1,2}\rangle$ and $|A_1\rangle$. This ratio, which is given by

$$\Gamma_{E_{1,2}}/\Gamma_{A_1} = \frac{2}{\pi} \hbar \eta \int_0^{\min(\Delta, \Omega)} \omega^3 \left(\frac{1}{\omega} - \frac{2}{\Delta + \Delta'} \right)^2 \times \frac{F(\Delta - \omega)}{F(\Delta)} d\omega, \quad (19)$$

has the advantage of being insensitive to the uncertainty in λ_\perp , which limits the precision of our determination of Δ . It is,

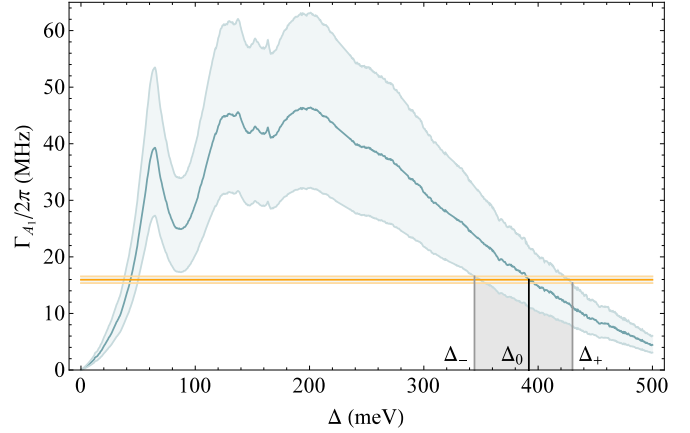


FIG. 5. (Color online) ISC rate from $|A_1\rangle$. The values of Γ_{A_1} calculated using Eq. (6) (blue line) and measured in Ref. [16] (orange line) are shown, with confidence intervals given by the uncertainty bounds on λ_\perp described in the text and the 95% confidence interval given for the measurement. The predicted range of Δ , which is defined by the intersection of the two curves, is shown in black. The points of intersection below 148 meV are excluded by the measured $\Gamma_{E_{1,2}}/\Gamma_{A_1}$ ratio, as explained in Sec. III B.

however, sensitive to uncertainty concerning the range of acoustic E -symmetric phonon modes that contribute to $\Gamma_{E_{1,2}}$. We use the expression for $\Gamma_{E_{1,2}}$ derived in the low-temperature limit [Eq. (12)], which we will justify at the end of this section. We use the value of $\eta = 2\pi \times (44.0 \pm 2.4)$ MHz meV $^{-3}$ extracted from a measurement of Γ_{Mix} as a function of temperature [16].

We analyze the $\Gamma_{E_{1,2}}/\Gamma_{A_1}$ ratio in both of the regions identified by our analysis of Γ_{A_1} : $\Delta \approx 43$ meV and 344 meV $\leq \Delta \leq 430$ meV. In the first region, shown in Fig. 6, the predicted ratio is significantly lower than the measured ratio, even when we assume no acoustic cutoff energy ($\Omega \rightarrow \infty$). This inconsistency excludes values of Δ up to 148 meV, which eliminates the $\Delta \approx 43$ meV region entirely. In the second region, we do not assume an infinite cutoff energy, but instead find the cutoff energy that would make the predicted ratio consistent with measurement, as shown in Fig. 6. Our analysis predicts an acoustic phonon cutoff energy Ω between 74 and 93 meV. This range coincides with a sharp and significant decline in the phonon spectral density extracted from the absorption PSB of the ${}^3A_2 \rightarrow {}^3E$ optical transition [29,37]. This agreement implies that the range of the predicted phonon cutoff energy is physically sensible, despite being near the upper limit of the acoustic phonon regime [38,39]. Our approximate expression for the phonon spectral density [Eq. (9)] is derived in the acoustic limit, but any correction that should be made to this approximation is swept into the phenomenological cutoff Ω . Hence, we conclude that the second region 344 meV $\leq \Delta \leq 430$ meV is fully consistent with the observed ISC rates.

We now support the assumption made in Sec. IID that we may neglect thermal occupation of the E -symmetric phonon modes that mediate the ISC from $|E_{1,2}\rangle$. In Fig. 7, we calculate the error due to neglecting the contribution to $|E_{1,2}\rangle$ due to stimulated emission and absorption of phonons. While this assumption would not be valid if either Δ or Ω were small, we

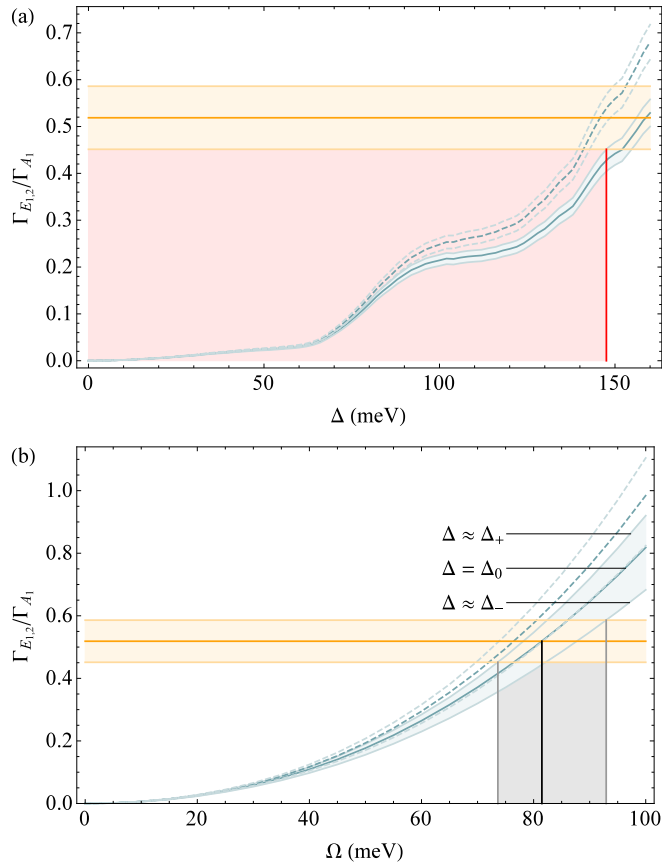


FIG. 6. (Color online) Ratio of the ISC rates from $|E_{1,2}\rangle$ and $|A_1\rangle$. The values of $\Gamma_{E_{1,2}}/\Gamma_{A_1}$ calculated using Eq. (19) (blue line) and measured in Ref. [16] (orange line, with 95% confidence interval) are shown. The dashed plots represent the results obtained when the ISC process that uses $|^1E_{1,2}\rangle$ as intermediate states is neglected (see Appendix). In (a), we assume no acoustic phonon cutoff ($\Omega \rightarrow \infty$), so the blue plot represents an upper bound on $\Gamma_{E_{1,2}}/\Gamma_{A_1}$. The calculated value's uncertainty is due to the uncertainty in η . This comparison excludes $\Delta < 148$ meV, as indicated by the red region. In (b), we use a range of Δ that corresponds approximately [35] to the range shown in Fig. 5, and we vary the acoustic cutoff energy Ω . The gray region represents the predicted range of Ω [36].

see that the resulting error is less than 1% for the values of Δ and Ω extracted from our analyses of Γ_{A_1} and $\Gamma_{E_{1,2}}/\Gamma_{A_1}$.

IV. EXTENSION TO HIGH TEMPERATURES

A. Method

We scale our model up to higher temperatures to compare the predicted lifetimes of the 3E states with $|m_s| = 1$ to measurements conducted at temperatures between 295 and 700 K [12–14]. In Secs. II C and II D, we calculated the ISC rates from $|A_1\rangle$ and $|E_{1,2}\rangle$ in the low-temperature limit.

Extension of the ISC model to higher temperatures requires three modifications to the ISC calculation: (1) Because of phonon-induced orbital averaging [40], which is significant even at $T \sim 20$ K [16], the observed ISC rate will be the average ISC rate from all 3E states with $|m_s| = 1$. (2) The E -symmetric phonon modes that mediate the ISC transition

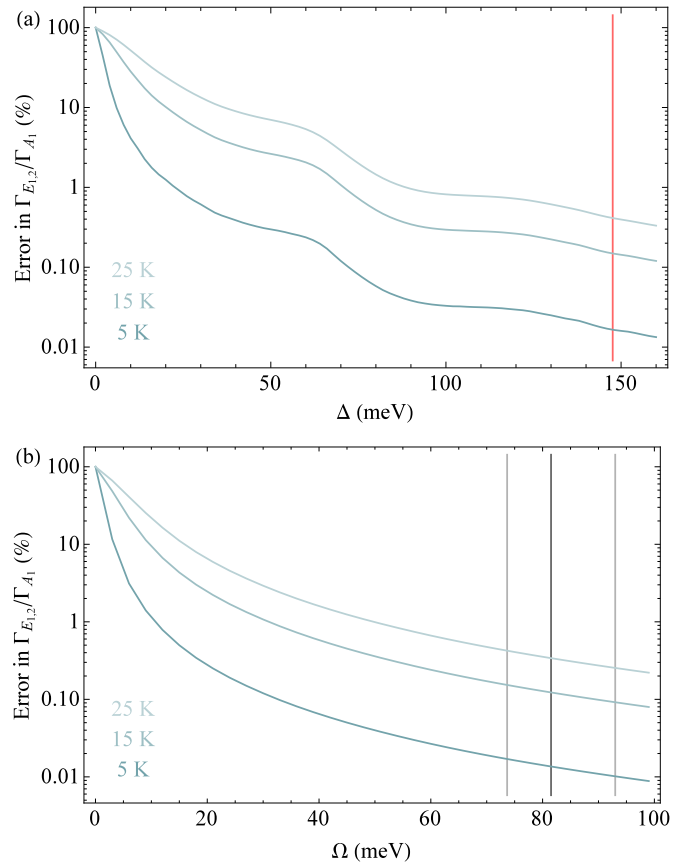


FIG. 7. (Color online) Error in $\Gamma_{E_{1,2}}/\Gamma_{A_1}$ ratio due to assumption of the low-temperature limit. The theoretical values of $\Gamma_{E_{1,2}}/\Gamma_{A_1}$ shown in Fig. 6 were calculated using Eq. (19), which neglects thermal occupation of the mediating phonon modes. We calculate the error due to working in the low-temperature limit by using the temperature-dependent expression for $\Gamma_{E_{1,2}}$ [Eq. (10)] rather than the temperature-independent expression [Eq. (12)]. We perform this calculation for the cases where (a) Ω is infinite and Δ is varied, and where (b) Δ is given by the values extracted from our analysis of Γ_{A_1} and Ω is varied. These are the same cases shown in Fig. 6 in the corresponding subfigures of Fig. 6. The results extracted from Fig. 6, the minimum allowed value of Δ in (a) and the expected values of Ω in (b), are shown to emphasize that the conclusions we draw using the low-temperature limit are valid.

from $|E_{1,2}\rangle$ have non-negligible thermal occupation. We must therefore consider ISC contributions due to stimulated and spontaneous emission into these modes, as well as absorption from these modes. (3) The A_1 -symmetric phonon modes that are primarily responsible for shifting the lattice from its 3E equilibrium configuration to its $|^1A_1\rangle$ equilibrium configuration have non-negligible thermal occupation, so the vibrational overlap function $F(\omega)$ becomes broader and flatter at higher temperatures.

To address modification (1), we calculate the orbitally averaged ISC rate

$$\Gamma_{\text{ISC}} = \frac{1}{4}(\Gamma_{A_1} + 2\Gamma_{E_{1,2}}), \quad (20)$$

where Γ_{A_1} is given by Eq. (6).

To address modification (2), we use $\Gamma_{E_{1,2}}$ as given by Eq. (10), which includes contributions due to both phonon

absorption and emission, instead of Eq. (12), which is calculated in the low-temperature limit.

To address modification (3), we calculate the temperature-dependent vibrational overlap function $F(\omega, T)$ using the procedure given in Ref. [29]. We first extract the low-temperature one-phonon spectral density $f(\omega)$ by numerically deconvolving the low-temperature phonon sideband $F(\omega)$, which was used in Secs. II C and II D to calculate the low-temperature ISC rates from $|A_1\rangle$ and $|E_{1,2}\rangle$. The resulting $f(\omega)$ is shown in red in Fig. 4 of Ref. [17], whose measurement of $F(\omega)$ we use throughout our analysis.

The temperature-dependent one-phonon vibrational overlap function is given by

$$F_1(\omega, T) = \begin{cases} [n(\omega, T) + 1] f(\omega) & \text{if } \omega \geq 0, \\ n(\omega, T) f(-\omega) & \text{if } \omega < 0. \end{cases} \quad (21)$$

Temperature-dependent multiphonon vibrational overlap functions can be calculated recursively using

$$\begin{aligned} F_i(\omega, T) &= F_{i-1}(\omega, T) \otimes F_1(\omega, T) \\ &= \int_{-\infty}^{\infty} F_{i-1}(\omega - \omega', T) F_1(\omega', T) d\omega' \end{aligned} \quad (22)$$

and then summed to find the total temperature-dependent vibrational overlap function

$$F(\omega, T) = e^{-S} \sum_{i=1}^{\infty} \frac{S^i}{i!} F_i(\omega, T). \quad (23)$$

Here,

$$S = S_0 \int_0^{\Omega} [2n(\omega', T) + 1] f(\omega') d\omega' \quad (24)$$

is the temperature-dependent Huang-Rhys factor, where $S_0 = 3.49$ is the low-temperature Huang-Rhys factor for the ${}^3E \rightarrow {}^3A_2$ transition [17].

In Fig. 8, we plot the calculated $F(\Delta, T)$ for temperatures between 0 and 700 K. We note a slight discrepancy between the measured low-temperature $F(\omega)$ and the calculated $F(\omega, T)$ at 0 K. There is a degree of imprecision inherent in this method

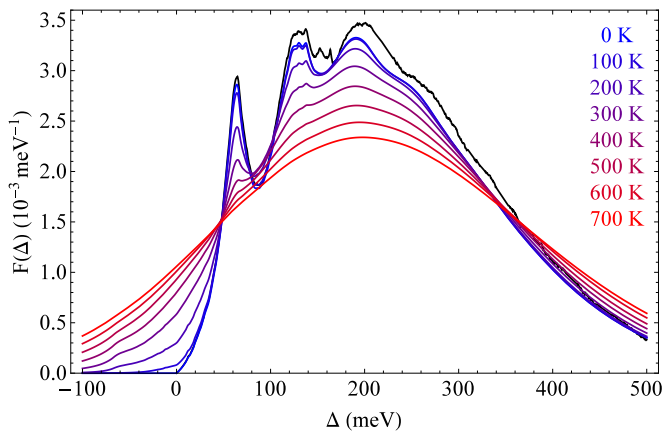


FIG. 8. (Color online) Calculated temperature-dependent vibrational overlap functions $F(\omega, T)$. The measured low-temperature vibrational overlap function $F(\omega)$ is shown in black [17].

of generating $F(\omega, T)$, but it should be sufficient to calculate the temperature trend of the theoretical ISC rates.

B. Results

We now numerically calculate the orbitally averaged ISC rate for the $|m_s| = 1$ states [Eq. (20)] using the temperature-dependent expressions for $\Gamma_{E_{1,2}}$ [Eq. (10)] and $F(\omega, T)$ [Eq. (23), plotted in Fig. 8]. We convert this ISC rate to the observed fluorescence lifetime using

$$\tau = \frac{1}{\Gamma_{\text{Rad}} + \Gamma_{\text{ISC}}}, \quad (25)$$

where $\Gamma_{\text{Rad}} = 2\pi \times (13.2 \pm 0.5)$ MHz is the radiative decay rate of states in the 3E manifold [16]. We use as numeric inputs the range of Δ and the associated values of Ω , extracted from the analyses shown in Figs. 5 and 6, that produce the measured $\Gamma_{E_{1,2}}/\Gamma_{A_1}$ ratio at low temperature.

We plot the results of this calculation (purple line), as well as the predicted temperature-independent lifetime of the $m_s = 0$ states (solid green line), in Fig. 9. We observe that the predicted lifetimes are consistent with experimental observations [12–14] for temperatures below 600 K. Above 600 K, it is clear that a temperature-dependent decay process for the $m_s = 0$ states switches on. This process may also shorten the average lifetime of the $|m_s| = 1$ states above 600 K, but the evidence for this assertion is not conclusive. This process has been previously attributed to a multiphonon nonradiative relaxation from 3E to $|{}^1A_1\rangle$ and described by a Mott-Seitz model [12]. We fit the high-temperature lifetime of the $m_s = 0$ states (dashed green line) using the Mott-Seitz model and the $|E_x\rangle$ lifetime of 12.0 ns that has been measured at low temperature [16] to obtain the temperature-dependent decay rate Γ_{HT} from the $m_s = 0$ states due to this high-temperature mechanism [41]. To incorporate Γ_{HT} into the predicted lifetime of the $|m_s| = 1$ states, we make the replacement $\Gamma_{\text{ISC}} \rightarrow \Gamma_{\text{ISC}} + \epsilon \Gamma_{\text{HT}}$ in Eq. (25), where ϵ parametrizes how strongly the high-temperature decay mechanism couples to the $|m_s| = 1$ states relative to the $m_s = 0$ states. The predicted high-temperature lifetimes are shown in Fig. 9. It is not obvious from the three relevant data points whether this high-temperature mechanism induces decay out of the $|m_s| = 1$ states as it does out of the $m_s = 0$ states.

The previous explanation given for the high-temperature decay is inconsistent with the model outlined in this work because there is no SO coupling between $|E_{x,y}\rangle$ and $|{}^1A_1\rangle$ and because phonons cannot couple $|E_{x,y}\rangle$ to $|A_1\rangle$, which is SO coupled to $|{}^1A_1\rangle$. Instead, we propose that one of two mechanisms may be responsible. First, this mechanism may be a SO-mediated transition from $|E_{x,y}\rangle$ to the excited spin-singlet $|{}^1E_{x,y}\rangle$ states. $|E_{x,y}\rangle$ are SO coupled to $|{}^1E_{x,y}\rangle$ just as $|A_1\rangle$ is SO coupled to $|{}^1A_1\rangle$, so this mechanism would be exactly analogous to the ISC mechanism from $|A_1\rangle$. This mechanism may induce decay from the $|m_s| = 1$ states because $|E_{x,y}\rangle$ are coupled to $|E_{1,2}\rangle$ by a spin-spin interaction [18,19]. Because $|E_y\rangle$ and $|E_{1,2}\rangle$ exhibit a level anticrossing when the strain-induced $|E_x\rangle - |E_y\rangle$ splitting is approximately 7 GHz [42], the spin-spin-mediated decay rate out of the $|m_s| = 1$ states would be highly sensitive to crystal strain, making it difficult to predict a value of ϵ for this mechanism.

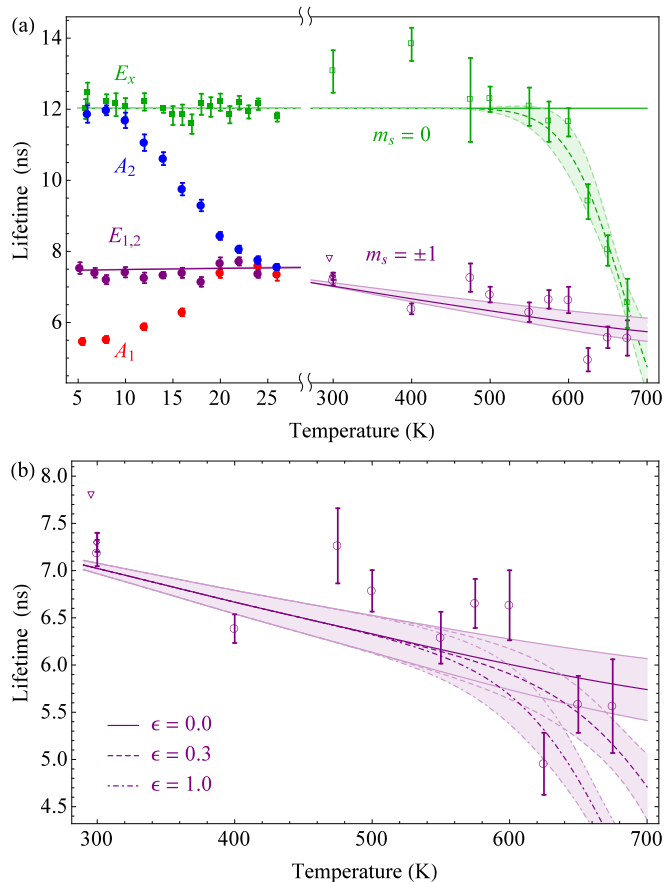


FIG. 9. (Color online) Comparison of the predicted high-temperature fluorescence lifetimes with measured lifetimes. The data from 5 to 26 K are taken from Ref. [16] and the data from 295 to 700 K are taken from Refs. [12] (\square and \circ), [14] (\diamond), and [13] (∇). In (a), the solid green line is the lifetime of the $m_s = 0$ states predicted by our model, and the dashed green line includes a fit to the Mott-Seitz model with 95% confidence interval, as described in the text. This decay mechanism is not included in the predicted lifetime of the $|m_s| = 1$ states. In (b), we plot the predicted lifetime of the $|m_s| = 1$ states with varying degrees of coupling to the high-temperature decay mechanism.

Alternatively, this mechanism may be a direct nonradiative transition to the 3A_2 ground state. E -symmetric phonons couple the states of the 3E and 3A_2 manifolds. Consequently, the calculation of this rate would be similar to that of the ISC rate from $|E_{1,2}\rangle$, except that this mechanism would be a first-order process that does not involve SO coupling in addition to phononic coupling. This mechanism would be spin conserving and couple to all 3E states equally, implying $\epsilon = 1$.

While the theory of these two possible high-temperature decay mechanisms is beyond the scope of this work, we emphasize that they can be distinguished by further high-temperature spin-resolved fluorescence lifetime experiments, which could reduce the uncertainty in the parameter ϵ and measure the variation of ϵ with strain.

V. CONCLUSION

We have presented a microscopic model of the ISC mechanism, which is mediated by spin-orbit coupling and, for some initial states, the emission of an E -symmetric phonon. We have quantitatively shown the model's predictions to be consistent with experimental observations, and have used this comparison to place bounds on the singlet-triplet energy spacing, an important but previously unknown property of the NV center's level structure.

The bounds we place on Δ have implications for efforts to engineer the ISC rate, which could increase the measurement readout visibility between $|0\rangle$ and $|\pm 1\rangle$ by increasing the ISC rate out of the $|m_s| = 1$ states. We estimate that the ISC rate increases by $2\pi \times (0.15 \pm 0.05)$ MHz/meV as Δ decreases. Because it is the competition of Γ_{ISC} with $\Gamma_{\text{Rad}} = 2\pi \times (13.2 \pm 0.5)$ MHz that gives rise to the fluorescence contrast between $|0\rangle$ and $|\pm 1\rangle$, our finding suggests that a large (~ 100 – 200 meV) reduction in Δ would be needed to achieve an appreciable improvement in nonresonant readout fidelity.

The application of isotropic hydrostatic pressure can induce large shifts (~ 400 meV [7]), but the direction of this shift corresponds to an increase in Δ , which would reduce the ISC rate. Conversely, the application of uniaxial strain (specifically along the [111] crystal axis) can induce energy shifts that reduce Δ , but the structural integrity of bulk diamond under unavoidable shear forces limits these shifts to ~ 10 meV [43,44]. It may be possible, however, to induce a suitably large shift in diamond nanofabricated structures [45,46], wherein the application of a small local force may cause a large strain at the NV center. One could measure this shift in the ISC rate either by the techniques employed in Ref. [16] or by measuring the visibility of ground-state optically detected magnetic resonance (ODMR) as in Ref. [7]. By identifying methods of strain application that maximize ODMR visibility, such an experiment could significantly enhance the spin initialization and readout techniques upon which room-temperature NV center applications depend.

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APPENDIX

We now consider the contribution to $\Gamma_{E_{1,2}}$ due to an ISC process that uses $|^1E_{1,2}\rangle$ as intermediate states instead of $|A_1\rangle$. In this process, $|E_{1,2}\rangle$ are SO coupled to $|^1E_{1,2}\rangle$, and phonons of E symmetry couple $|^1E_{1,2}\rangle$ to $|^1A_1\rangle$. We modify Eq. (7), with which we begin our calculation of $\Gamma_{E_{1,2}}$, to include the

contribution of this secondary process, finding

$$\Gamma_{E_{1,2}} = 2\pi\hbar^3 \sum_{n,p,k} |\sqrt{2}\lambda_{\perp}\lambda_{p,k}|^2 \delta(v_n + \omega_k - \Delta) \times \left| \frac{\langle \chi_0 | \chi'_{v_n} \rangle}{\omega_k} - \sum_{n'} \frac{2\langle \chi_0 | \chi''_{v_{n'}} \rangle \langle \chi''_{v_{n'}} | \chi'_{v_n} \rangle}{\Delta + \Delta' - v_{n'}} \right|^2, \quad (\text{A1})$$

where $|\chi''_{v_{n'}}\rangle$ is an excited vibrational level of $|^1E_{1,2}\rangle$ that is separated from $|^1E_{1,2}\rangle$ by an energy spacing $v_{n'}$ and Δ' is the $|^1A_1\rangle - |^1E_{1,2}\rangle$ energy splitting. We add the two contributions' amplitudes instead of their magnitudes because the final states arrived at by both processes are identical for given values of n , p , and k . The two terms have opposite signs because the phonon is emitted first (second) for the mechanism using $|A_1\rangle$ ($|E_{1,2}\rangle$) as an intermediate state, making the detuning denominator $\mathcal{E}_i - \hat{H}_0$ negative (positive).

Because the energy spacing $\Delta + \Delta'$ ($387 \pm 43 + 1190$ meV [28]) is large compared to the extent of the phonon sideband (~ 500 meV [17,29]), we make the simplifying assumption that $\langle \chi_0 | \chi''_{v_{n'}} \rangle$ is only appreciable for $v_{n'} \ll \Delta + \Delta'$. We use this approximation, the expression for the phonon

spectral density in the acoustic regime given by Eq. (9), and the identity operator $\hat{1} = \sum_{n'} |\chi''_{v_{n'}}\rangle \langle \chi''_{v_{n'}}|$ to find

$$\Gamma_{E_{1,2}} = 8\hbar^2\lambda_{\perp}^2\eta \int_0^{\Omega} \omega^3 \sum_n \delta(v_n + \omega - \Delta) \times \left| \left(\frac{1}{\omega} - \frac{2}{\Delta + \Delta'} \right) \langle \chi_0 | \chi'_{v_n} \rangle - \sum_{n'} \frac{2v_{n'} \langle \chi_0 | \chi''_{v_{n'}} \rangle \langle \chi''_{v_{n'}} | \chi'_{v_n} \rangle}{(\Delta + \Delta')^2} \right|^2 d\omega. \quad (\text{A2})$$

Finally, we neglect the last term, which is a second-order correction in $v_{n'}, \omega \ll \Delta + \Delta'$, to find

$$\Gamma_{E_{1,2}} = 8\hbar^2\lambda_{\perp}^2\eta \int_0^{\Omega} \omega^3 \left(\frac{1}{\omega} - \frac{2}{\Delta + \Delta'} \right)^2 F(\Delta - \omega) d\omega. \quad (\text{A3})$$

This expression trivially reduces to Eq. (12) for $\Delta' \rightarrow \infty$. This modification constitutes a $\sim 15\%$ downward correction to $\Gamma_{E_{1,2}}$ for the relevant values of Δ and Ω , as shown in Fig. 6.

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